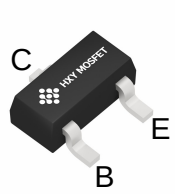
BC817

NPN Plastic-Encapsulate Transistors

Features

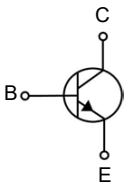
- Collector Current: I_C=0.5A
- Power Dissipation of 300mW



SOT-23

Package Marking and Ordering Information

Product ID	Pack	Qty(PCS)
BC817-16/25/40	SOT-23	3000



Maxmim Ratings (Ta=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	500	mA
Collector Power Dissipation	P_C	300	mW
Thermal Resistance From Junction To Ambient	$R_{\Theta JA}$	417	℃/W
Junction Temperature	T_j	150	℃
Storage Temperature	T_{stg}	-55～+150	℃

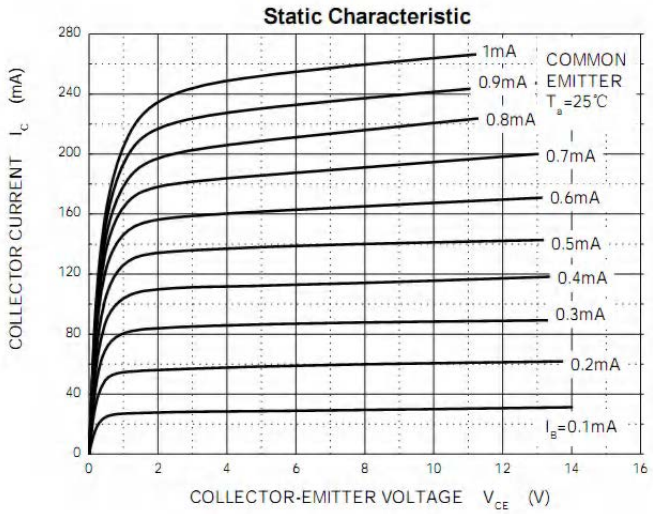
Classifiction Of h_{FE}

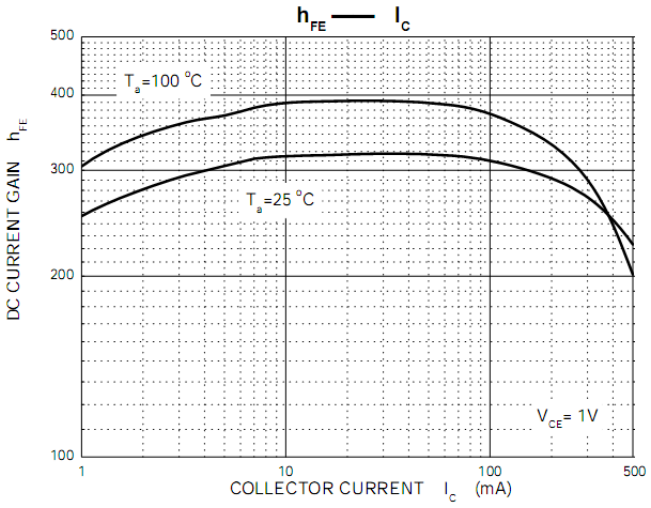
Rank	BC817-16	BC817-25	BC817-40
Range	100-250	160-400	250-600
Marking	6A	6B	6C

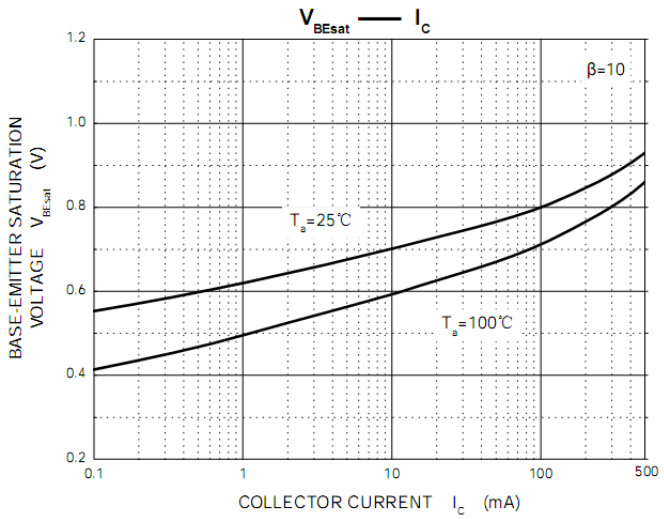
Electrcal Charcteristics (T_a=25℃ unless otherwise specified)

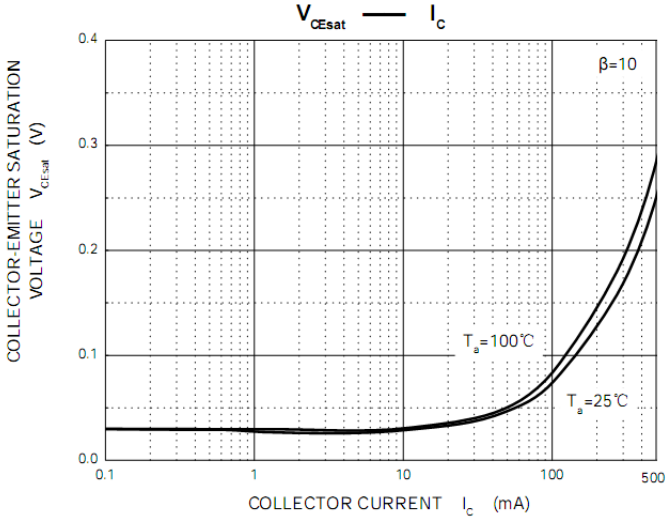
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V_{CBO}	I_C= 10μA, I_E=0	50			V
Collector-emitter breakdown voltage	V_{CEO}	I_C= 10mA, I_B=0	45			V
Emitter-base breakdown voltage	V_{EBO}	I_E= 1μA , I_C=0	5			V
Collector cut-off current	I_{CBO}	V_{CB}= 45 V , I_E=0			0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB}= 4V, I_C=0			0.1	μA
DC current gain	$h_{FE(1)}$	V_{CE}= 1V, I_C= 100mA	100		600	
	$h_{FE(2)}$	V_{CE}= 1V, I_C= 500mA	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C= 500mA, I_B= 50mA			0.7	V
Base-emitter saturation voltage	$V_{BE(sat)}$	I_C= 500mA, I_B= 50mA			1.2	V
Base-emitter voltage	V_{BE}	V_{CE}= 1 V, I_C= 500mA			1.2	V
Collecter capactiance	C_{ob}	V_{CB}=10V ,f=1MHz		10		pF
Transition frequency	f_T	V_{CE}= 5 V, I_C= 10mA f=100MHz	100			MHz

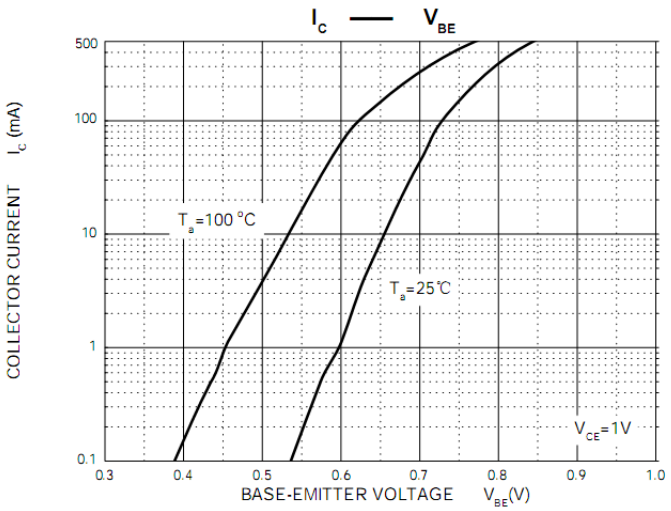
Typical Characteristics

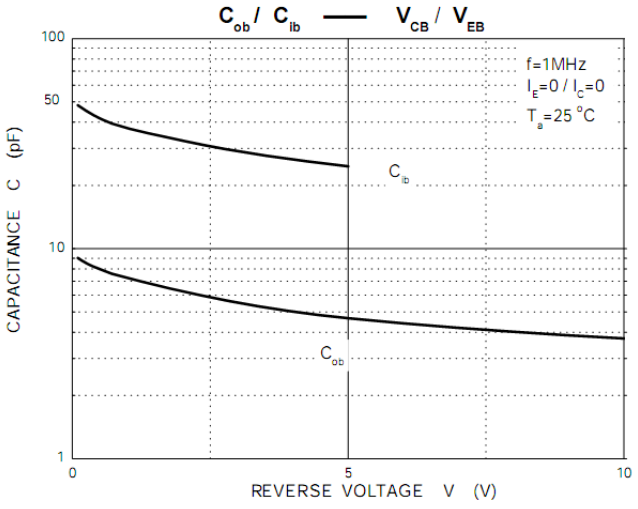


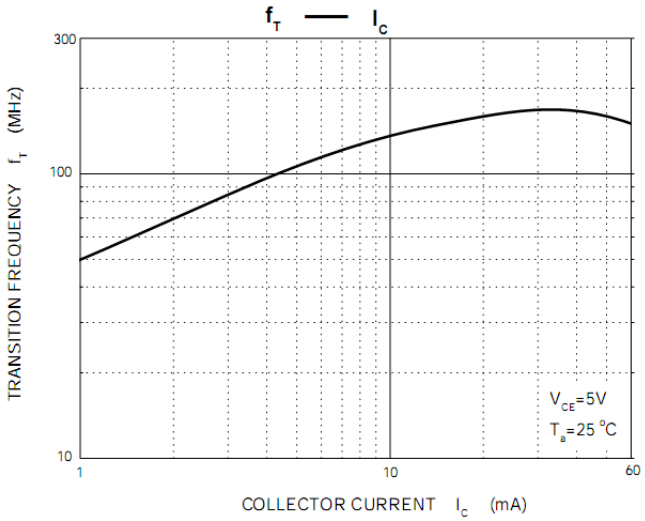


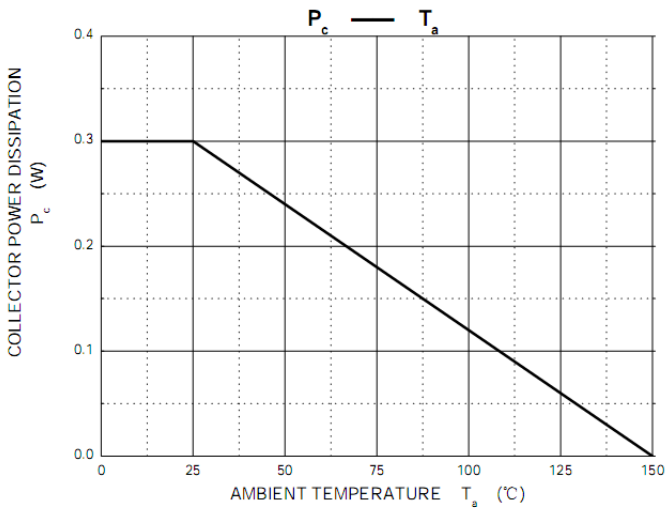

V_{BEsat} — I_C
β=10
T_a=25℃
T_a=100℃
BASE-EMITTER SATURATION VOLTAGE V_{BEsat} (V)
COLLECTOR CURRENT I_C (mA)


V_{CEsat} — I_C
β=10
T_a=100℃
T_a=25℃
COLLECTOR-EMITTER SATURATION VOLTAGE V_{CEsat} (V)
COLLECTOR CURRENT I_C (mA)

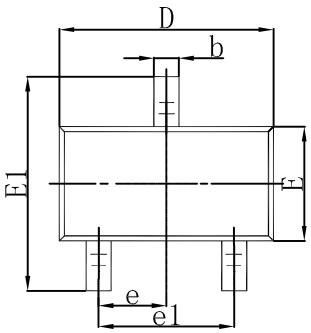

I_C — V_{BE}
T_a=100 °C
T_a=25℃
V_{CE}=1V
COLLECTOR CURRENT I_C (mA)
BASE-EMITTER VOLTAGE V_{BE}(V)

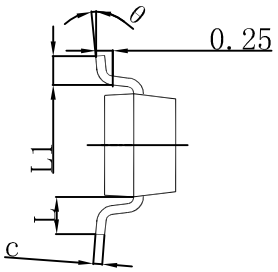

C_{ob} / C_{ib} — V_{CB} / V_{EB}
f=1MHz
I_E=0 / I_C=0
T_a=25 °C
C_{ib}
C_{ob}
CAPACITANCE C (pF)
REVERSE VOLTAGE V (V)

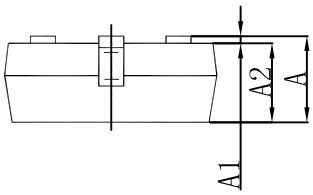

f_T — I_C
V_{CE}=5V
T_a=25 °C
TRANSITION FREQUENCY f_T (MHz)
COLLECTOR CURRENT I_C (mA)


P_c — T_a
COLLECTOR POWER DISSIPATION P_c (W)
AMBIENT TEMPERATURE T_a (℃)

SOT-23 Package Outline Dimensions

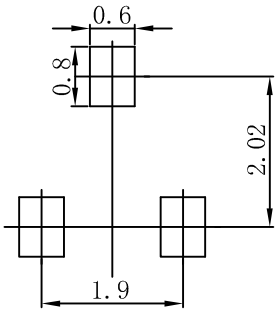






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

Attention

■ Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.

■ HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.

■ Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

■ HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could
give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

■ In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

■ Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

■ Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.